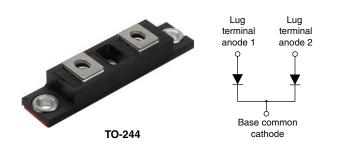
Vishay Semiconductors

High Performance Schottky Rectifier, 400 A



www.vishay.com

PRODUCT SUMMARY				
I _{F(AV)}	400 A			
V _R	45 V			
Package	TO-244			
Circuit	Two diodes common cathode			

FEATURES

- 150 °C T_J operation
- Center tap module
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- UL approved file E222165
- · Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-400CNQ045PbF center tap, high current, Schottky rectifier module has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform	400	А				
V _{RRM}		45	V				
I _{FSM}	t _p = 5 μs sine	29 000	А				
V _F	200 A _{pk} , T _J = 125 °C (per leg)	0.52	V				
TJ	Range	-55 to 150	°C				

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-400CNQ045PbF	UNITS
Maximum DC reverse voltage	V _R	45	V
Maximum working peak reverse voltage	V _{RWM}	45	v

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward currentper leg			50.04		200		
See fig. 5	per device	$I_{F(AV)}$ 50 % duty cycle at T _C = 114 °C, rectangular waveform		400	А		
Maximum peak one cycle non-repetitive			5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	29 000		
surge current per leg See fig. 7		I _{FSM}	FSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	3400	
Non-repetitive avalanche energy pe	r leg	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 19 \text{ A}, L = 1 \text{ mH}$		180	mJ	
Repetitive avalanche current per leg		I _{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T_J maximum V_A = 1.5 x V_R typical		40	А	

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COMPLIANT



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ELECTRICA	L SPECI	FICATIO	DNS

PARAMETER	SYMBOL	TEST C	VALUES	UNITS	
		200 A	T ₁ = 25 °C	0.57	
Maximum forward voltage drop per leg	V _{EM} ⁽¹⁾	400 A	1)=23 0	0.73	v
See fig. 1	VFM (**	200 A	T _{.1} = 125 °C	0.52	v
		400 A	1j = 125 C	0.7	1
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated V _B	20	mA
See fig. 2	IRM (''	T _J = 125 °C	$v_{\rm R}$ = Rated $v_{\rm R}$	1.2	А
Threshold voltage	V _{F(TO)}	$T_{J} = T_{J}$ maximum		0.32	V
Forward slope resistance	r _t			0.81	mΩ
Maximum junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		10 300	pF
Typical series inductance per leg	L _S	From top of terminal hole to mounting plane		5.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs	

Note

Γ

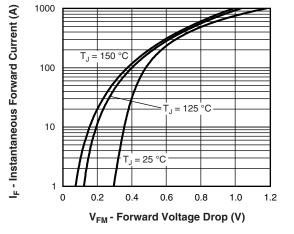
 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}	-55	-	150	°C	
Thermal resistance, junction to case per leg	P	-	-	0.19		
Thermal resistance, junction to case per module	R _{thJC}	-	-	0.095	°C/W	
Thermal resistance, case to heatsink	R _{thCS}	-	0.10	-		
Weight		-	68	-	g	
		-	2.4	-	oz.	
Mounting torque		35.4 (4)		53.1 (6)		
Mounting torque center hole		30 (3.4)		40 (4.6)	lbf · in (N · m)	
Terminal torque		30 (3.4)	-	44.2 (5)		
Vertical pull		-	-	80	line in	
2" lever pull		-	-	35	lbf ⋅ in	

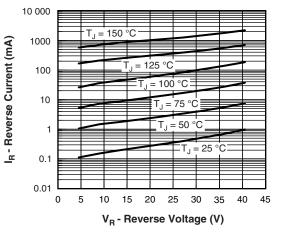


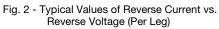
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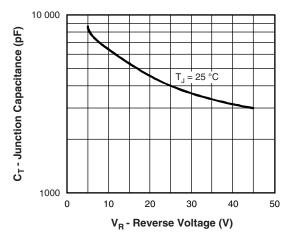
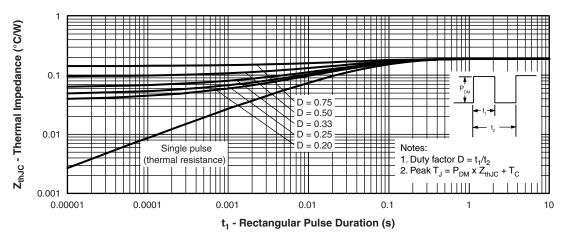


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)



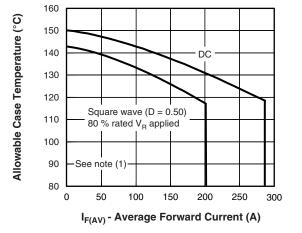


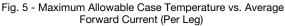
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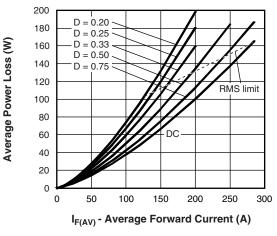
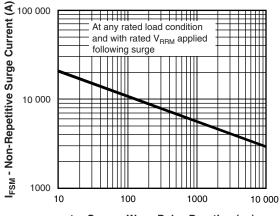


Fig. 6 - Forward Power Loss Characteristics (Per Leg)



t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

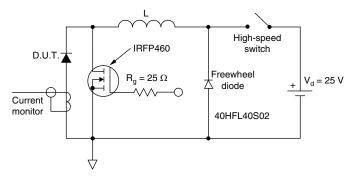


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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ORDERING INFORMATION TABLE

Device code	VS-	40	0	С	Ν	Q	045	PbF
		2	3	4	5	6	7	8
	 Vishay Semiconductors product Average current rating (x 10) Product silicon identification C = Circuit configuration 							
	5 - N = Not isolated							
	6	Q =	Schottk	ky rectifi	er diode)		
	7 -	Vol	tage rati	ng (045	= 45 V))		
	8 -	Lea	ıd (Pb)-f	ree				

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95021			

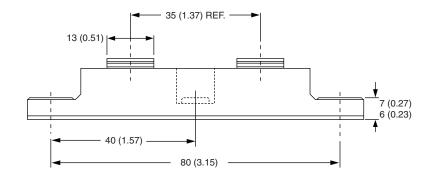


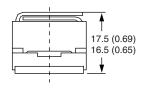


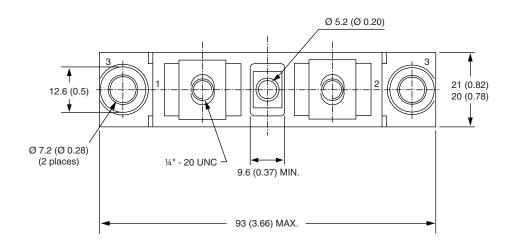
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TO-244

DIMENSIONS in millimeters (inches)









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